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16-Channel, Constant-Current LED Driver with LED Open Detection

FEATURES

- **16 Channels, Constant Current Sink Output with On/Off Control**
- **35-mA Capability (Constant Current Sink)**
- **10-ns High-Speed Constant Current Switching Transient Time**
- **Low On-Time Error**
- **LED Power-Supply Voltage up to 17 V**
- **V_{CC} = 3.0 V to 5.5 V**
- **Constant Current Accuracy:**
  - **Channel-to-Channel = ±1%**
  - **Device-to-Device = ±1%**
- **CMOS Logic Level I/O**
- **35-MHz Data Transfer Rate**
- **20-ns BLANK Pulse Width**
- **Readable Error Information:**
  - **LED Open Detection (LOD)**
  - **Pre-Thermal Warning (PTW)**
- **Operating Temperature: –40°C to +85°C**

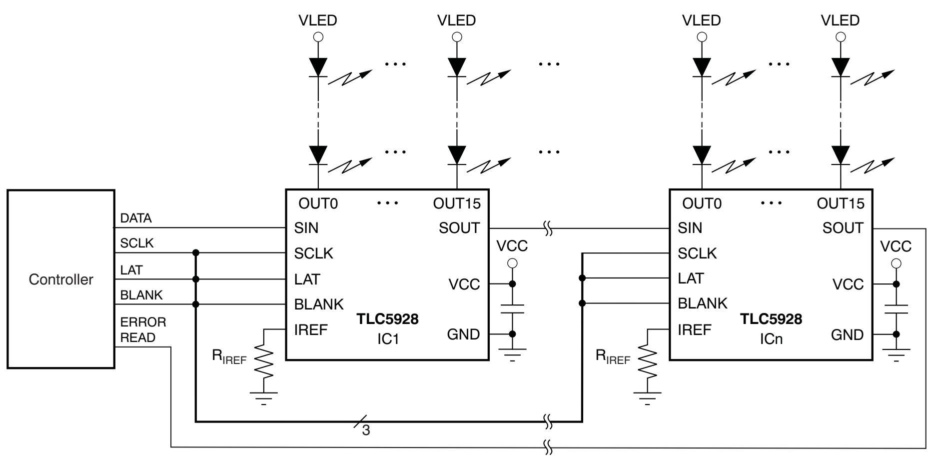
APPLICATIONS

- **LED Video Displays**
- **Message Boards**
- **Illumination**

DESCRIPTION

The TLC5928 is a 16-channel, constant current sink LED driver. Each channel can be turned on/off by writing serial data to an internal register. The constant current value of all 16 channels is set by a single external resistor.

The TLC5928 has two error detection circuits: one for LED open detection (LOD) and one for a pre-thermal warning (PTW). LOD detects a broken or disconnected LED and LEDs shorted to GND while the constant current output is on. PTW indicates a high temperature condition.



Typical Application Circuit (Multiple Daisy-Chained TLC5928s)

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE-LEAD	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
TLC5928	SO-24	TLC5928DBQR	Tape and Reel, 2500
		TLC5928DBQ	Tube, 50
TLC5928	TSSOP-24	TLC5928PWR	Tape and Reel, 2000
		TLC5928PW	Tube, 60
TLC5928	HTSSOP-24 PowerPAD™	TLC5928PWPR	Tape and Reel, 2000
		TLC5928PWP	Tube, 60
TLC5928	QFN-24	TLC5928RGER	Tape and Reel, 3000
		TLC5928RGE	Tape and Reel, 250

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS(1)(2)

Over operating free-air temperature range, unless otherwise noted.

PARAMETER			TLC5928	UNIT
V_{CC}	Supply voltage: V_{CC}		–0.3 to +6.0	V
I_{OUT}	Output current (dc)	OUT0 to OUT15	40	mA
V_{IN}	Input voltage range	SIN, SCLK, LAT, BLANK, IREF	–0.3 to V_{CC} + 0.3	V
V_{OUT}	Output voltage range	SOUT	–0.3 to V_{CC} + 0.3	V
		OUT0 to OUT15	–0.3 to +18	V
$T_{J(MAX)}$	Operating junction temperature		+150	°C
T_{STG}	Storage temperature range		–55 to +150	°C
	ESD rating	Human body model (HBM)	2	kV
		Charged device model (CDM)	500	V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.
(2) All voltage values are with respect to network ground terminal.

DISSIPATION RATINGS

PACKAGE	OPERATING FACTOR ABOVE T_A = +25°C	T_A < +25°C POWER RATING	T_A = +70°C POWER RATING	T_A = +85°C POWER RATING
SO-24	14.3 mW/°C	1782 mW	1140 mW	927 mW
TSSOP-24	9.6 mW/°C	1194 mW	764 mW	621 mW
HTSSOP-24(1)	28.9 mW/°C	3611 mW	2311 mW	1878 mW
QFN-24(2)	24.8 mW/°C	3106 mW	1988 mW	1615 mW

(1) With PowerPAD soldered onto copper area on printed circuit board (PCB); 2 oz. copper. For more information, see SLMA002 (available for download at www.ti.com).
(2) The package thermal impedance is calculated in accordance with JESD51-5.

RECOMMENDED OPERATING CONDITIONS

At T_A= –40°C to +85°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	TLC5928 MIN	NOM	MAX	UNIT
DC Characteristics: V_{CC} = 3 V to 5.5 V						
V_{CC}	Supply voltage		3.0		5.5	V
V_O	Voltage applied to output	OUT0 to OUT15			17	V
V_{IH}	High-level input voltage		0.7 × V_{CC}		V_{CC}	V
V_{IL}	Low-level input voltage		GND		0.3 × V_{CC}	V
I_{OH}	High-level output current	SOUT			–1	mA
I_{OL}	Low-level output current	SOUT			1	mA
I_{OLC}	Constant output sink current	OUT0 to OUT15	2		35	mA
T_A	Operating free-air temperature range		–40		+85	°C
T_J	Operating junction temperature range		–40		+125	°C
AC Characteristics: V_{CC} = 3 V to 5.5 V						
$f_{CLK\ (SCLK)}$	Data shift clock frequency	SCLK			35	MHz
T_{WH0}	Pulse duration	SCLK	10			ns
T_{WL0}		SCLK	10			ns
T_{WH1}		LAT	20			ns
T_{WH2}		BLANK	20			ns
T_{WL2}		BLANK	20			ns
T_{SU0}	Setup time	SIN–SCLK↑	4			ns
T_{SU1}		LAT↑–SCLK↑	100			ns
T_{H0}	Hold time	SIN–SCLK↑	3			ns
T_{H1}		LAT↑–SCLK↑	10			ns

ELECTRICAL CHARACTERISTICS

At V_{CC} = 3.0 V to 5.5 V and T_A = –40°C to +85°C. Typical values at V_{CC} = 3.3 V and T_A = +25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	TLC5928 MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	I_{OH} = –1 mA at SOUT	V_{CC} – 0.4		V_{CC}	V
V_{OL}	Low-level output voltage	I_{OL} = 1 mA at SOUT	0		0.4	V
I_{IN}	Input current	V_{IN} = V_{CC} or GND at SIN, SCLK, LAT, and BLANK	–1		1	µA
I_{CC1}	Supply current (V_{CC})	SIN/SCLK/LAT = low, BLANK = high, V_{OUTn} = 1 V, R_{IREF} = 27 kΩ		1	2	mA
I_{CC2}		SIN/SCLK/LAT = low, BLANK = high, V_{OUTn} = 1 V, R_{IREF} = 3 kΩ		4.5	8	mA
I_{CC3}		SIN/SCLK/LAT/BLANK = low, V_{OUTn} = 1 V, R_{IREF} = 3 kΩ		7	18	mA
I_{CC4}		SIN/SCLK/LAT/BLANK = low, V_{OUTn} = 1 V, R_{IREF} = 1.5 kΩ		16	40	mA
I_{OLC}	Constant output current	All OUTn = ON, V_{OUTn} = V_{OUTfix} = 1 V, R_{IREF} = 1.5 kΩ (see Figure 6), at OUT0 to OUT15	31	34	37	mA
I_{OLKG}	Output leakage current	All OUTn for constant current driver, all outputs off BLANK = high, V_{OUTn} = V_{OUTfix} = 17 V, R_{IREF} = 1.5 kΩ (see Figure 6), at OUT0 to OUT15			0.1	µA
ΔI_{OLC}	Constant current error (channel-to-channel)(1)	All OUTn = ON, V_{OUTn} = V_{OUTfix} = 1 V, R_{IREF} = 1.5 kΩ at OUT0 to OUT15		±1	±3	%
ΔI_{OLC1}	Constant current error (device-to-device)(2)	All OUTn = ON, V_{OUTn} = V_{OUTfix} = 1 V, R_{IREF} = 1.5 kΩ at OUT0 to OUT15		±1	±6	%
ΔI_{OLC2}	Line regulation(3)	All OUTn = ON, V_{OUTn} = V_{OUTfix} = 1 V, R_{IREF} = 1.5 kΩ at OUT0 to OUT15		±0.5	±1	%/V
ΔI_{OLC3}	Load regulation(4)	All OUTn = ON, V_{OUTn} = 1 V to 3V, V_{OUTfix} = 1 V, R_{IREF} = 1.5 kΩ, at OUT0 to OUT15		±1	±3	%/V
$T_{(PTW)}$	Pre-thermal warning threshold	Junction temperature(5)	+125	+138	+150	°C
V_{LOD}	LED open detection threshold	All OUTn = ON	0.25	0.30	0.35	V
V_{IREF}	Reference voltage output	R_{IREF} = 1.5 kΩ	1.16	1.20	1.24	V

(1) The deviation of each output from the average of OUT0–OUT15 constant current. Deviation is calculated by the formula:

$$\Delta(\%) = \left(\frac{I_{OUTn}}{\dfrac{(I_{OUT0} + I_{OUT1} + \dots + I_{OUT14} + I_{OUT15})}{16}} - 1 \right) \times 100$$

(2) The deviation of the OUT0–OUT15 constant current average from the ideal constant current value. Deviation is calculated by the following formula:

$$\Delta(\%) = \left(\frac{\dfrac{(I_{OUT0} + I_{OUT1} + \dots I_{OUT14} + I_{OUT15})}{16} - (\text{Ideal Output Current})}{\text{Ideal Output Current}} \right) \times 100$$

Ideal current is calculated by the formula:

$$I_{OUT(IDEAL)} = 42 \times \left(\frac{1.20}{R_{IREF}} \right)$$

(3) Line regulation is calculated by this equation:

$$\Delta(\%/V) = \left(\frac{(I_{OUTn} \text{ at } V_{CC} = 5.5\text{ V}) - (I_{OUTn} \text{ at } V_{CC} = 3.0\text{ V})}{(I_{OUTn} \text{ at } V_{CC} = 3.0\text{ V})} \right) \times \frac{100}{5.5\text{ V} - 3\text{ V}}$$

(4) Load regulation is calculated by the equation:

$$\Delta(\%/V) = \left(\frac{(I_{OUTn} \text{ at } V_{OUTn} = 3\text{ V}) - (I_{OUTn} \text{ at } V_{OUTn} = 1\text{ V})}{(I_{OUTn} \text{ at } V_{OUTn} = 1\text{ V})} \right) \times \frac{100}{3\text{ V} - 1\text{ V}}$$

(5) Not tested. Specified by design.

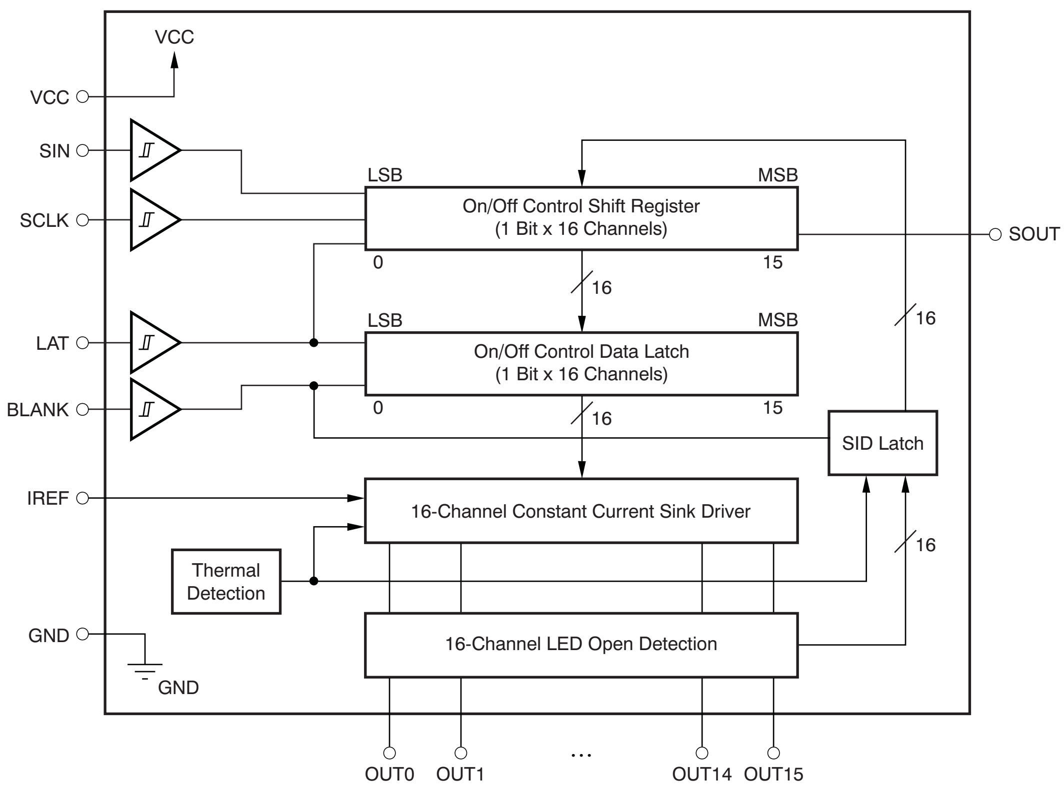
SWITCHING CHARACTERISTICS

At V_{CC} = 3.0 V to 5.5 V, T_A = –40°C to +85°C, C_L = 15 pF, R_L = 130 Ω, R_{IREF} = 1.5 kΩ, and V_{LED} = 5.5 V. Typical values at V_{CC} = 3.3 V and T_A = +25°C, unless otherwise noted.

PARAMETER		TEST CONDITIONS	TLC5928 MIN	TLC5928 TYP	TLC5928 MAX	UNIT
t_{R0}	Rise time	SOUT (see Figure 5)		5	15	ns
t_{R1}	Rise time	OUTn (see Figure 4)		10	30	ns
t_{F0}	Fall time	SOUT (see Figure 5)		5	15	ns
t_{F1}	Fall time	OUTn (see Figure 4)		10	30	ns
t_{D0}	Propagation delay time	SCLK↑ to SOUT		8	20	ns
t_{D1}	Propagation delay time	LAT↑ or BLANK↓ to OUTn sink current on (see Figure 10)		12	30	ns
t_{D2}	Propagation delay time	LAT↑ or BLANK↑ to OUTn sink current off (see Figure 10)		12	30	ns
t_{ON_ERR}	Output on-time error(1)	On/off latch data = all '1', 20 ns BLANK low level one-shot pulse input (see Figure 4)	–8		+8	ns

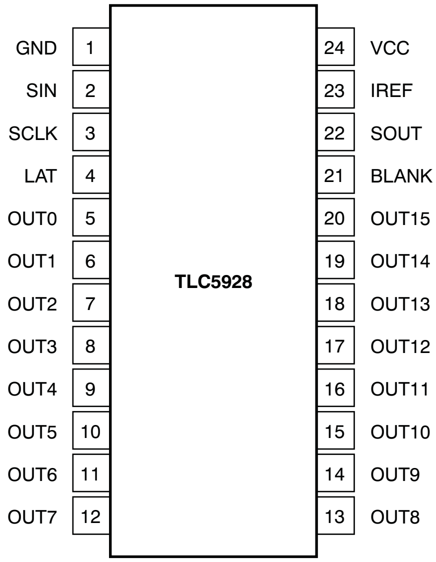
(1) Output on-time error (t_{ON_ERR}) is calculated by the formula: t_{ON_ERR} (ns) = t_{OUT_ON} – BLANK low level one-shot pulse width (T_{WL2}). t_{OUT_ON} indicates the actual on-time of the constant current driver.

FUNCTIONAL BLOCK DIAGRAM

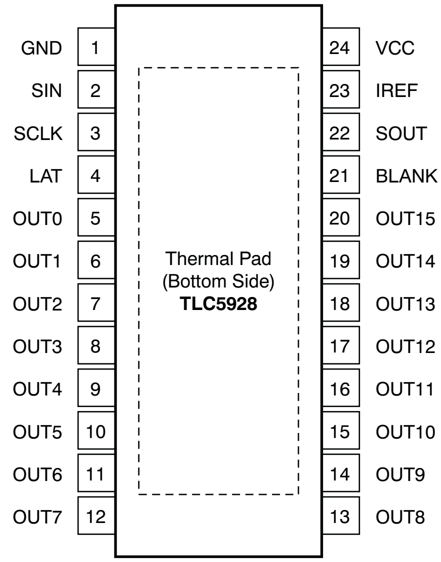


DEVICE INFORMATION

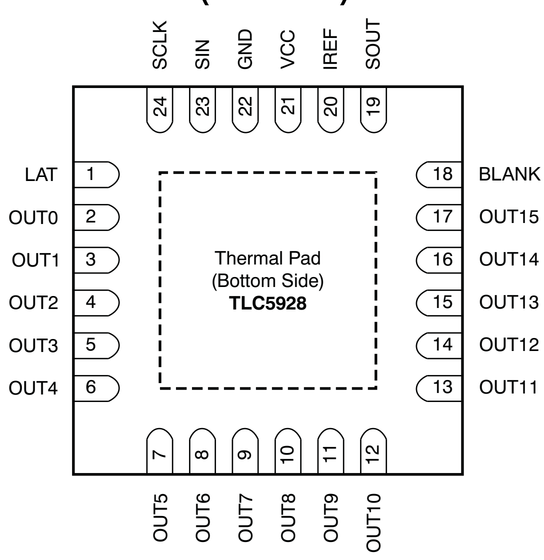
SO-24 AND TSSOP-24 DBQ AND PW PACKAGES (TOP VIEW)



HTSSOP-24 PowerPAD PWP PACKAGE (TOP VIEW)



QFN-24 RGE PACKAGE (TOP VIEW)



NOTE: Thermal pad is not connected to GND internally. The thermal pad must be connected to GND via the PCB pattern.

TERMINAL FUNCTIONS

TERMINAL				
NAME	DBQ/PW/ PWP	RGE	I/O	DESCRIPTION
SIN	2	23	I	Serial data input for driver on/off control. When SIN = high level, data '1' are written into LSB of the on/off control shift register at the rising edge of SCLK.
SCLK	3	24	I	Serial data shift clock. Schmitt buffer input. All data in the on/off control shift register are shifted toward the MSB by 1-bit synchronization of SCLK. A rising edge on SCLK is allowed 100 ns after a rising edge of LAT.
LAT	4	1	I	Edge triggered latch. The data in the on/off control data shift register are transferred to the on/off control data latch at this rising edge. At the same time, the data in the on/off control shift register are replaced with LED open detection (LOD) and pre-thermal warning (PTW) data. LAT must be toggled only once after the shift data are updated to avoid the on/off control latch data being replaced with LOD and PTW data in the shift register.
BLANK	21	18	I	Blank, all outputs. When BLANK = high level, all constant current outputs (OUT0–OUT15) are forced off. When BLANK = low level, all constant current outputs are controlled by the on/off control data in the data latch. LOD and PTW data are latched into the SID data latch at the rising edge of BLANK and are present at the output of the SID data latch when BLANK is low.
IREF	23	20	I/O	Constant current value setting, OUT0–OUT15 sink constant current is set to desired value by connection to an external resistor between IREF and GND.
SOUT	22	19	O	Serial data output. This output is connected to the MSB of the on/off data shift register. SOUT data changes at the rising edge of SCLK.
OUT0	5	2	O	Constant current output. Each output can be tied together with others to increase the constant current. Different voltages can be applied to each output.
OUT1	6	3	O	Constant current output
OUT2	7	4	O	Constant current output
OUT3	8	5	O	Constant current output
OUT4	9	6	O	Constant current output
OUT5	10	7	O	Constant current output
OUT6	11	8	O	Constant current output
OUT7	12	9	O	Constant current output
OUT8	13	10	O	Constant current output
OUT9	14	11	O	Constant current output
OUT10	15	12	O	Constant current output
OUT11	16	13	O	Constant current output
OUT12	17	14	O	Constant current output
OUT13	18	15	O	Constant current output
OUT14	19	16	O	Constant current output
OUT15	20	17	O	Constant current output
VCC	24	21	—	Power-supply voltage
GND	1	22	—	Power ground

PARAMETER MEASUREMENT INFORMATION

PIN EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS

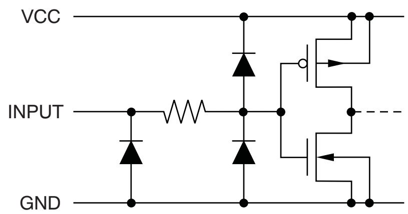


Figure 1. SIN, SCLK, LAT, BLANK

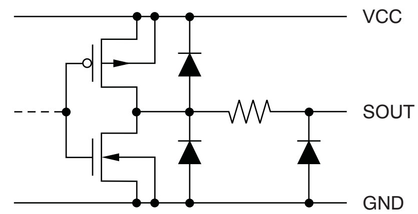


Figure 2. SOUT

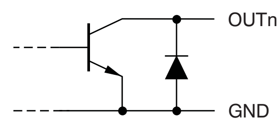
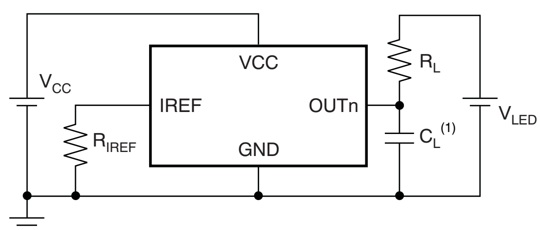


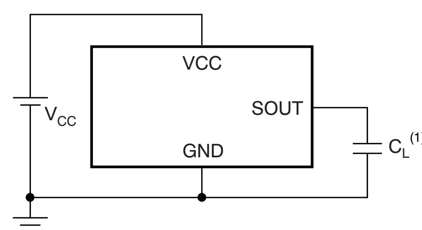
Figure 3. OUT0 Through OUT15

TEST CIRCUITS



(1) C_L includes measurement probe and jig capacitance.

Figure 4. Rise Time and Fall Time Test Circuit for OUTn



(1) C_L includes measurement probe and jig capacitance.

Figure 5. Rise Time and Fall Time Test Circuit for SOUT

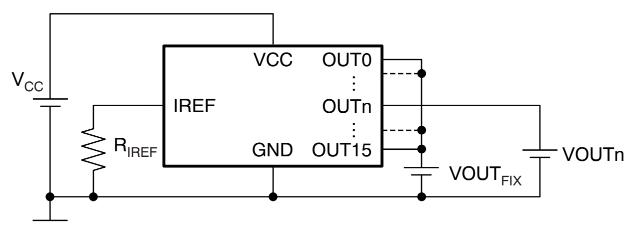
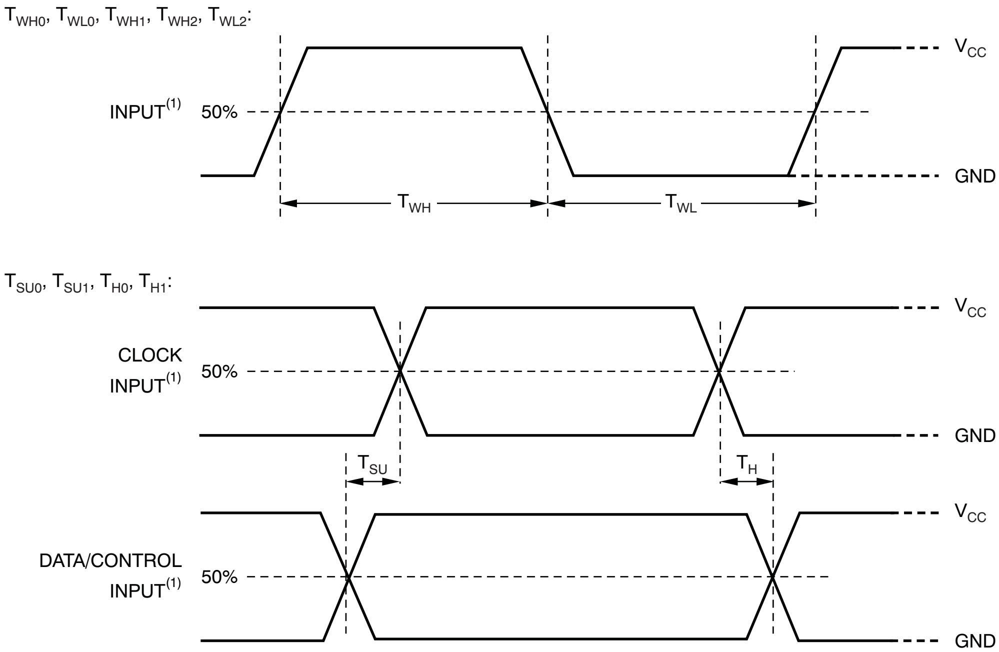


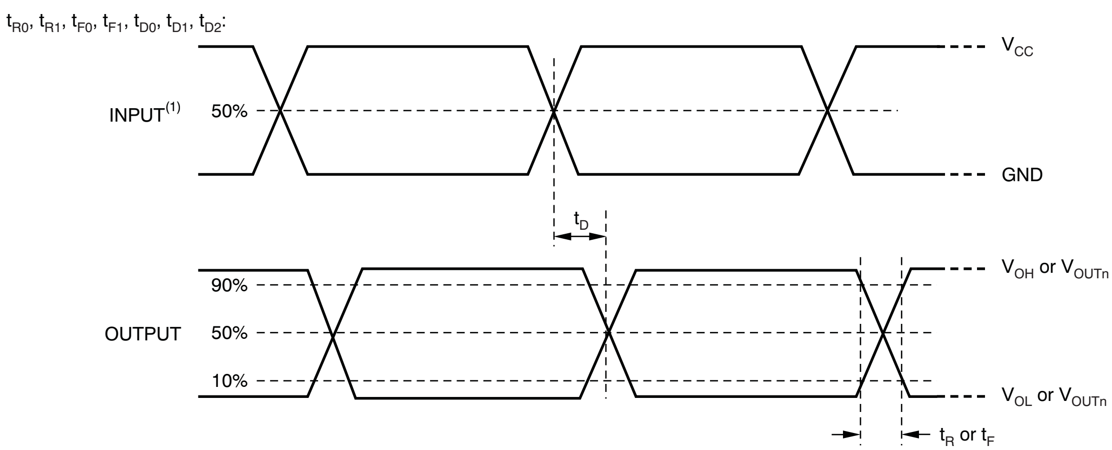
Figure 6. Constant Current Test Circuit for OUTn

TIMING DIAGRAMS



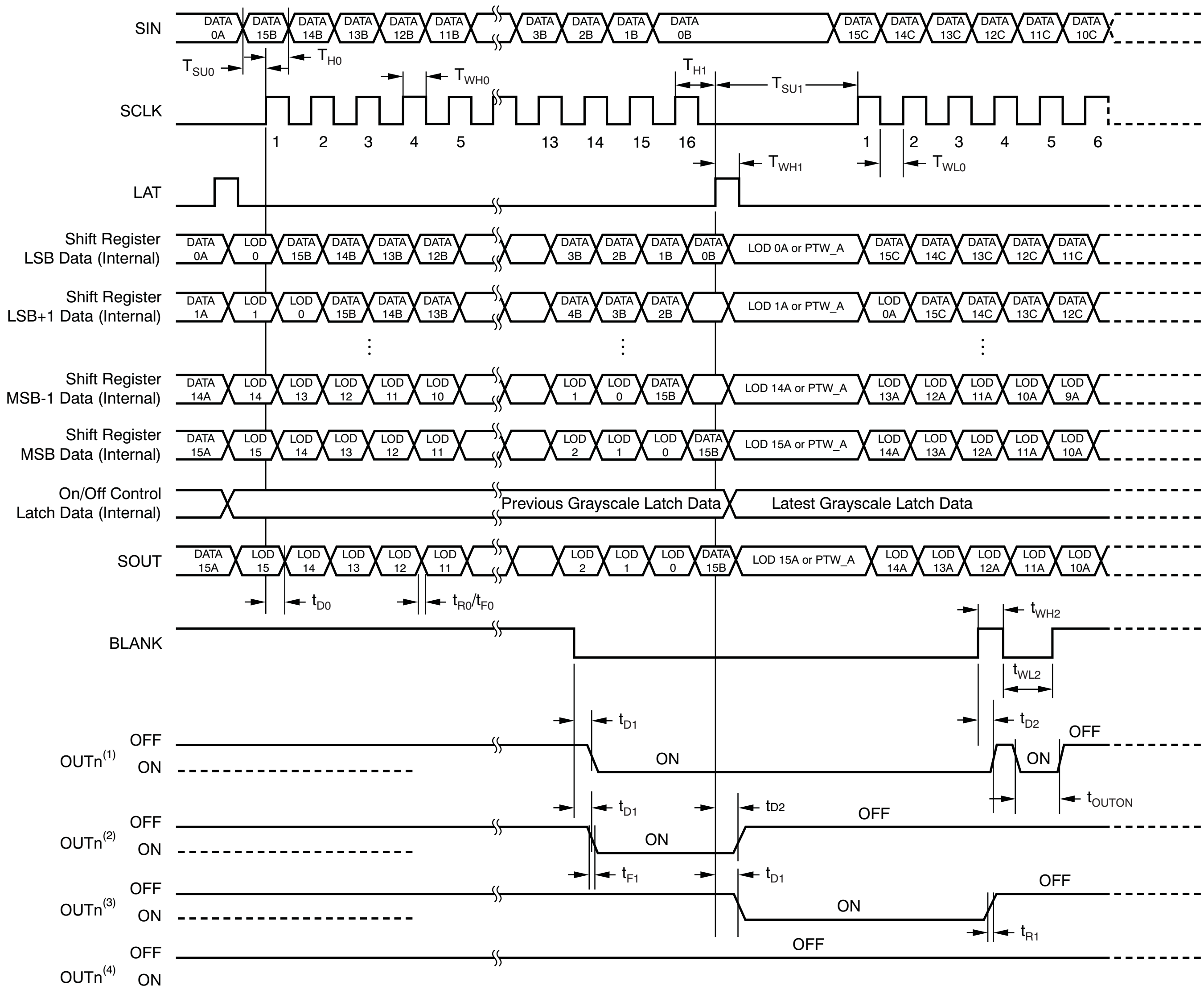
(1) Input pulse rise and fall time is 1 ns to 3 ns.

Figure 7. Input Timing



(1) Input pulse rise and fall time is 1 ns to 3 ns.

Figure 8. Output Timing



(1) On/off latched data are '1'.

(2) On/off latched data are changed from '1' to '0' at the second LAT signal.

(3) On/off latched data are changed from '0' to '1' at the second LAT signal.

(4) On/off latched data are '0'.

Figure 9. Timing Diagram

TYPICAL CHARACTERISTICS

At V_{CC} = 3.3 V and T_A = +25°C, unless otherwise noted.

REFERENCE RESISTOR vs OUTPUT CURRENT

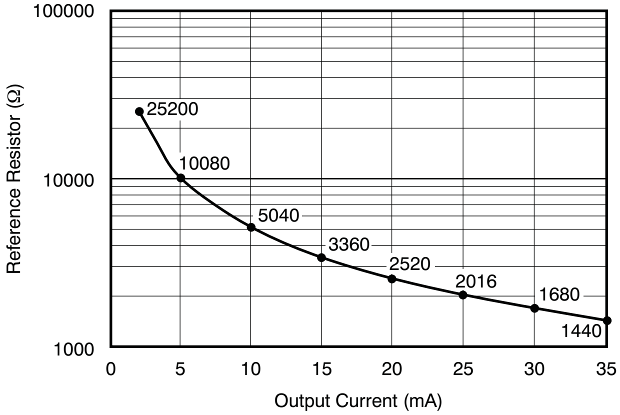


Figure 10.

POWER DISSIPATION RATE vs FREE-AIR TEMPERATURE

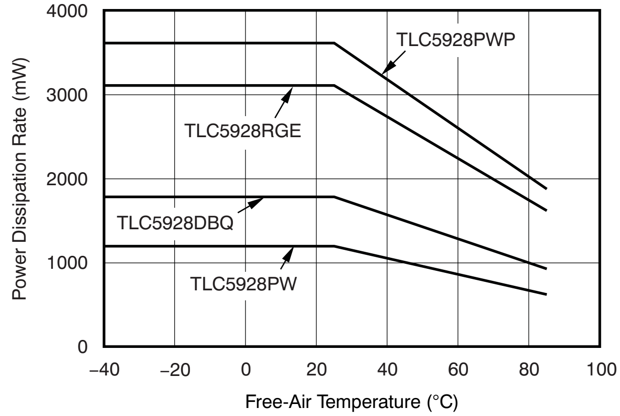


Figure 11.

OUTPUT CURRENT vs OUTPUT VOLTAGE

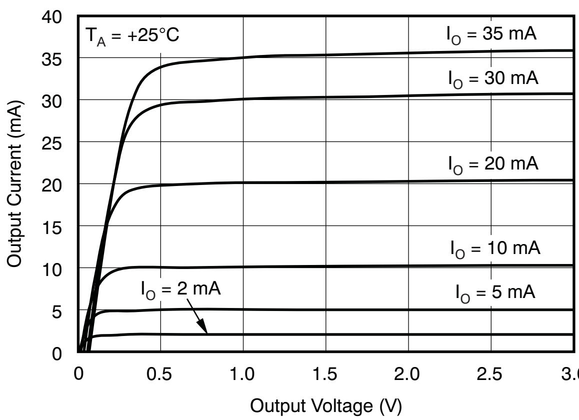


Figure 12.

OUTPUT CURRENT vs OUTPUT VOLTAGE

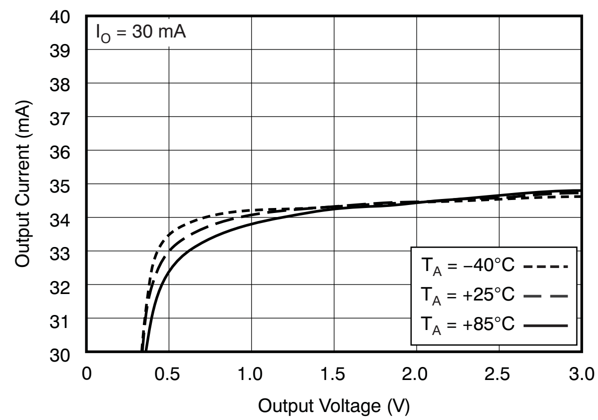


Figure 13.

ΔI_{OLC} vs AMBIENT TEMPERATURE

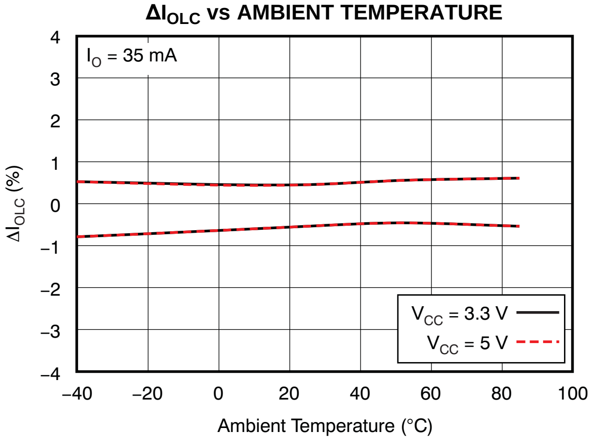


Figure 14.

ΔI_{OLC} vs OUTPUT CURRENT

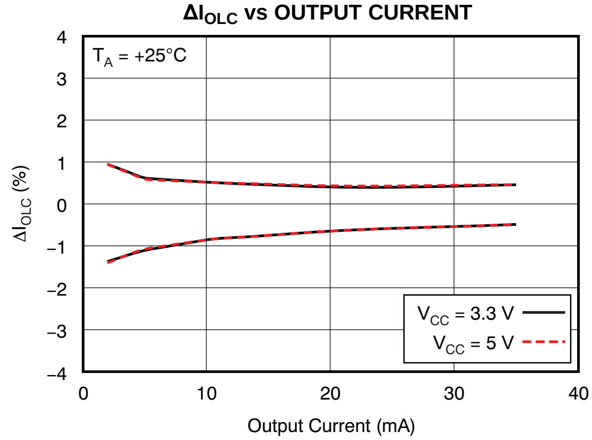


Figure 15.

TYPICAL CHARACTERISTICS (continued)

At V_{CC} = 3.3 V and T_A = +25°C, unless otherwise noted.

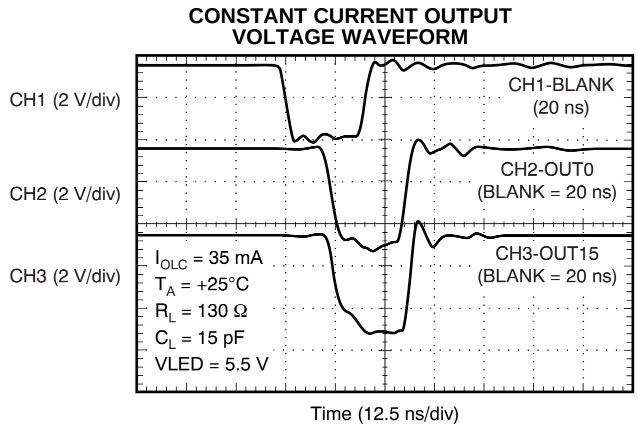


Figure 16.

DETAILED DESCRIPTION

SETTING FOR THE CONSTANT SINK CURRENT VALUE

The constant current values are determined by an external resistor (R_{IREF}) placed between IREF and GND. The resistor (R_{IREF}) value is calculated by Equation 1.

$$R_{IREF}\,(k\Omega) = \frac{V_{IREF}\,(V)}{I_{OLC}\,(mA)} \times 42 \quad (1)$$

Where:

V_{IREF} = the internal reference voltage on the IREF pin (typically 1.20 V)

I_{OLC} must be set in the range of 2 mA to 35 mA. The constant sink current characteristic for the external resistor value is shown in Figure 10. Table 1 describes the constant current output versus external resistor value.

Table 1. Constant Current Output versus External Resistor Value

I_{OLCMax} (mA, Typical)	R_{IREF} (kΩ)
35	1.44
30	1.68
25	2.02
20	2.52
15	3.36
10	5.04
5	10.1
2	25.2

CONSTANT CURRENT DRIVER ON/OFF CONTROL

When BLANK is low, the corresponding output is turned on if the data in the on/off control data latch are '1' and remains off if the data are '0'. When BLANK is high, all outputs are forced off. This control is shown in Table 2.

Table 2. On/Off Control Data Truth Table

ON/OFF CONTROL LATCH DATA	CONSTANT CURRENT OUTPUT STATUS
0	Off
1	On

When the IC is initially powered on, the data in the on/off control shift register and data latch are not set to the respective default value. Therefore, the on/off control data must be written to the data latch before turning the constant current output on. BLANK should be at a high level when powered on because the constant current may be turned on as a result of random data in the on/off control latch.

The on/off data corresponding to any unconnected OUTn outputs should be set to '0' before turning on the remaining outputs. Otherwise, the supply current (I_{CC}) increases while the LEDs are on.

REGISTER CONFIGURATION

The TLC5928 has an on/off control data shift register and data latch. Both the on/off control shift register and latch are 16 bits long and are used to turn on/off the constant current drivers. Figure 17 shows the shift register and latch configuration. The data at the SIN pin are shifted in to the LSB of the shift register at the rising edge of the SCLK pin; SOUT data change at the rising edge of SCLK. The timing diagram for data writing is shown in Figure 18. The driver on/off is controlled by the data in the on/off control data latch.

The on/off data are latched into the data latch by a rising edge of LAT after the data are written into the on/off control shift register by SIN and SCLK. At the same time, the data in the on/off control shift register are replaced with LED open detection (LOD) and pre-thermal warning (PTW) data. Therefore, LAT must be input only once after the on/off data update to avoid the on/off control data latch being replaced with LOD and PTW data in the shift register. When the IC is initially powered on, the data in the on/off control shift register and latch are not set to the default values; on/off control data must be written to the on/off control data latch before turning the constant current output on. BLANK should be high when the IC is powered on because the constant current may be turned on at that time as a result of random values in the on/off data latch. All constant current outputs are forced off when BLANK is high.

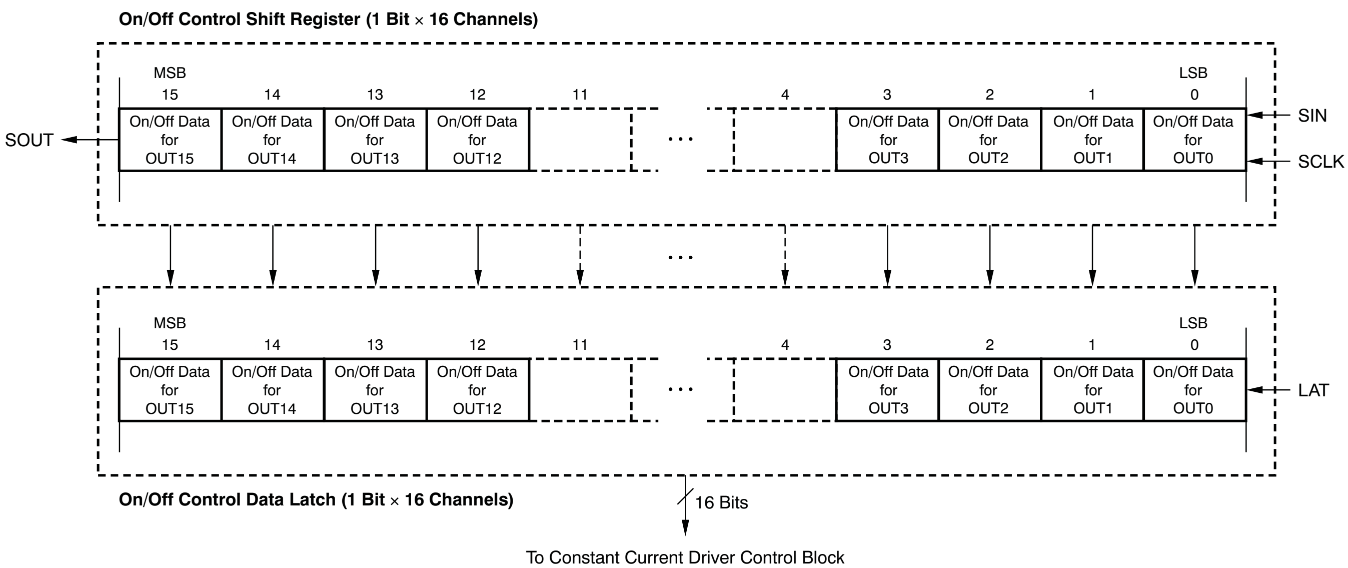
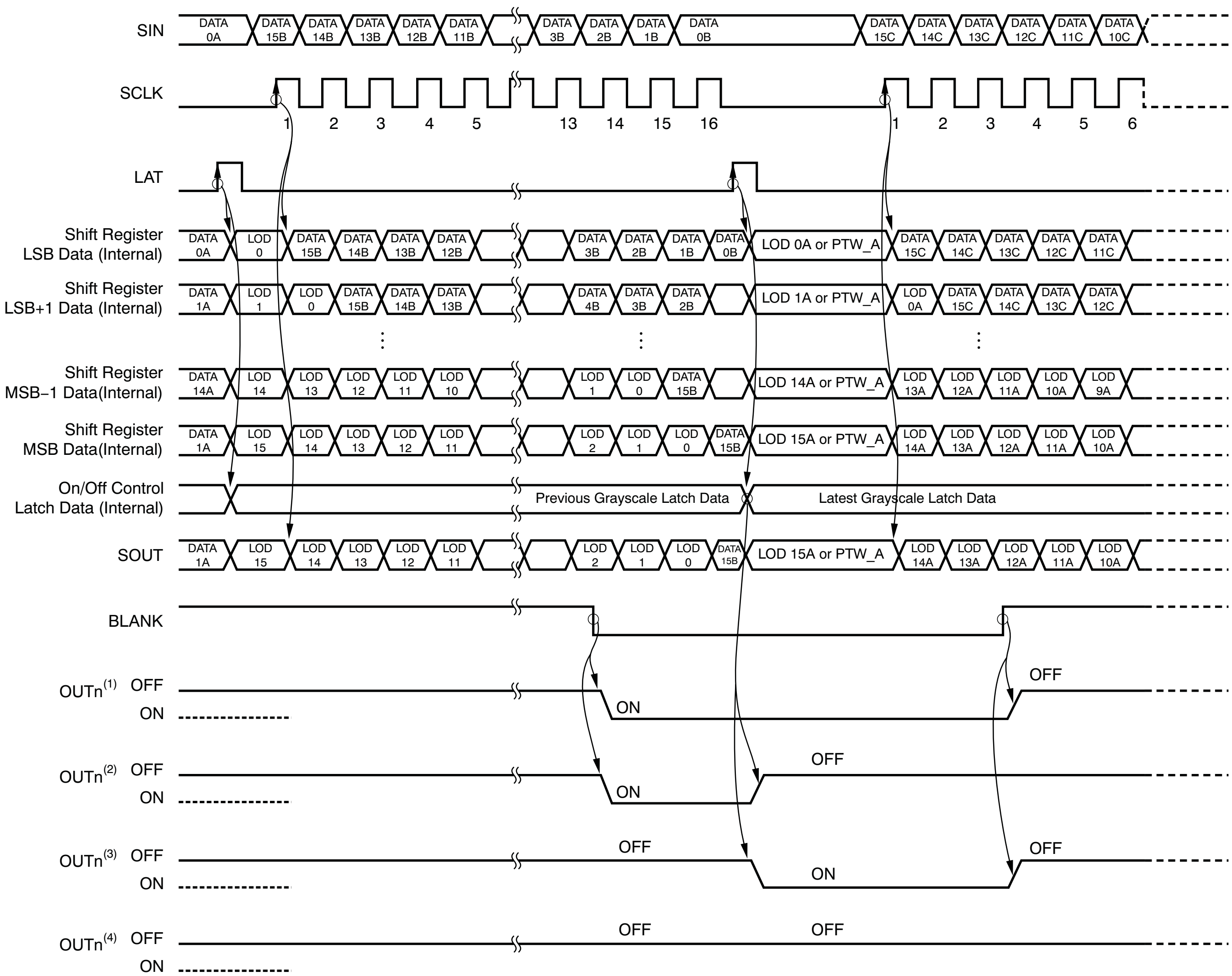


Figure 17. On/Off Control Shift Register and Latch Configuration



(1) On/off latched data are '1'.

(2) On/off latched data are changed from '1' to '0' at the second LAT signal.

(3) On/off latched data are changed from '0' to '1' at the second LAT signal.

(4) On/off latched data are '0'.

Figure 18. On/Off Control Operation

LED OPEN DETECTION (LOD) AND PRE-THERMAL WARNING (PTW)

The LED open detection (LOD) circuit checks the voltage of each active (that is, on) constant current sink output (OUT0 through OUT15) to detect open LEDs and LEDs shorted to GND while BLANK is low. The LOD bits in the status information data register (SID) are set to '1' if the voltage of the corresponding OUTn pin is less than the LED open detection threshold (V_{LOD} = 0.3 V, typ). The status information data can be read from the SOUT pin. To avoid false detection of open LEDs, the LED driver design must ensure that the constant-current sink output voltage is greater than 0.3 V when the outputs are on. Also, the output on-time must be 1 µs or greater to correctly read the valid LOD status.

The PTW function indicates that the IC junction temperature is too high. The PTW bit in the SID data is set to '1' while the IC junction temperature exceeds the temperature threshold ($T_{(PTW)}$ = +138 °C, typ). If the IC junction temperature decreases below the temperature of $T_{(PTW)}$, the SID data are set depending on the LOD function. The constant current outputs are not forced off during PTW conditions, so the controller should take appropriate action (such as reducing the duty cycle of effected channels).

The LOD and PTW data are latched into the SID latch with the rising edge of BLANK and do not change until BLANK goes low. The SID data latched in the latch are transferred into the on/off shift register with a rising edge of LAT. SID can be shifted out from SOUT with rising edges of SCLK. The data in the on/off control shift register are replaced with the LOD and PTW data at the rising edge of LAT. Therefore, LAT should be input only once after the shift data are updated to avoid the on/off control data latch information from being replaced with LOD and PTW data in the shift register. A timing diagram for LOD, PTW, and SID is shown in Figure 19.

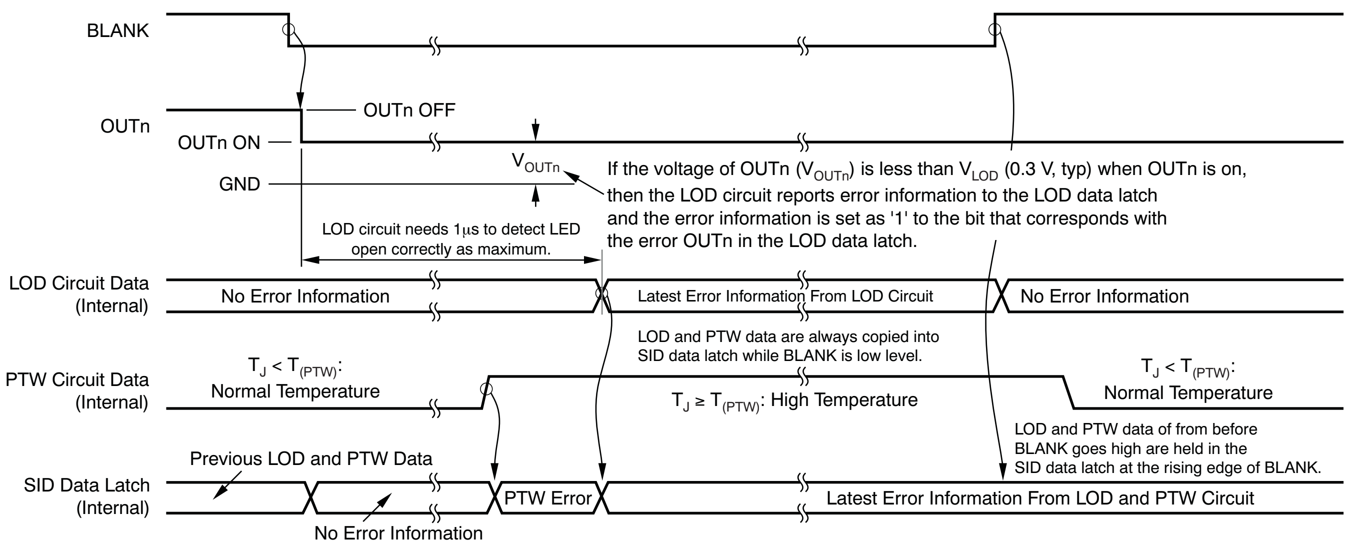


Figure 19. LOD/PTW/SID timing

STATUS INFORMATION DATA (SID)

The latched LED open detection (LOD) error and pre-thermal warning (PTW) in the SID data latch are shifted out onto the SOUT pin with each rising edge of SCLK. If a PTW is reported, all LOD error bits are set to '1'. The SID data are written over the data in the on/off control shift register at the rising edge of LAT. Therefore, the previous data in the on/off control shift register are lost when SID information is latched in. Figure 20 shows the SID bit assignments. See Figure 7 for the read timing of SID.

When the IC is powered on, the initial LOD data are invalid. Therefore, LOD data must be read after the rising edge of BLANK. Table 3 shows a truth table for LOD and PTW.

Table 3. LOD and PTW Truth Table

	CONDITION	SID DATA
LED open detection (LODn)	LED is connected ($V_{OUTn} > V_{LOD}$)	'0' (low level at SOUT)
	LED is opened or shorted to GND ($V_{OUTn} \le V_{LOD}$ and output on)	'1' (high level at SOUT); set to the bit that has an LED error condition
Pre-thermal warning (PTW)	IC temperature is low (IC temperature ≤ $T_{(PTW)}$)	Depend LED open error
	IC temperature is high (IC temperature > $T_{(PTW)}$)	All bits = '1' (high level at SOUT)

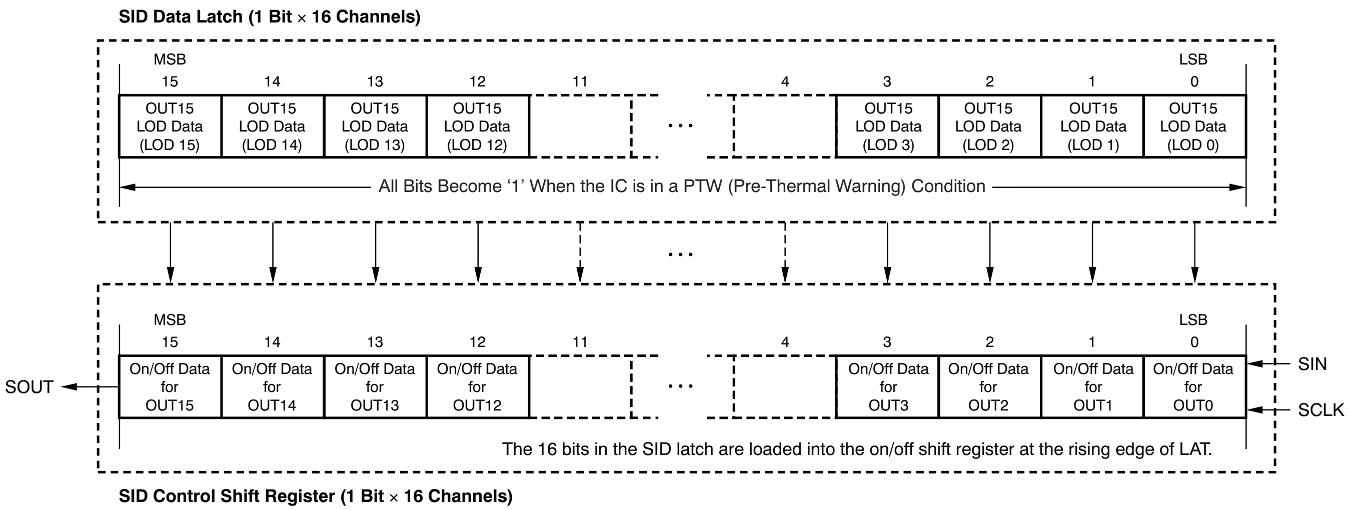


Figure 20. Status Information Data Configuration

Revision History

Changes from Revision B (October 2008) to Revision C **Page**

Changes from Revision A (September 2008) to Revision B **Page**

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
TLC5928DBQ	ACTIVE	SSOP/ QSOP	DBQ	24	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928DBQG4	ACTIVE	SSOP/ QSOP	DBQ	24	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928DBQR	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928DBQRG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC5928PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC5928PWP	ACTIVE	HTSSOP	PWP	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928PWPG4	ACTIVE	HTSSOP	PWP	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928PWPR	ACTIVE	HTSSOP	PWP	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928PWPRG4	ACTIVE	HTSSOP	PWP	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC5928PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC5928RGER	ACTIVE	VQFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TLC5928RGET	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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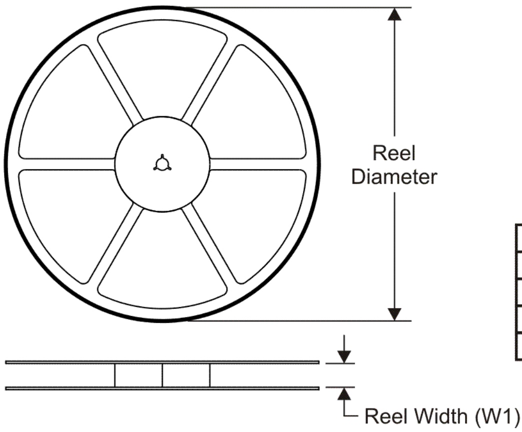
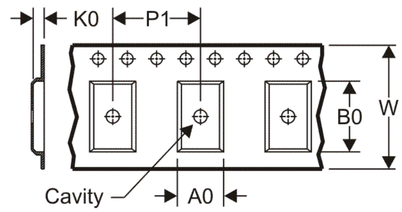
TAPE AND REEL INFORMATION

REEL DIMENSIONS

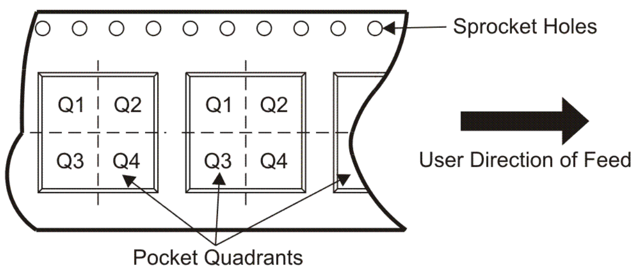


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

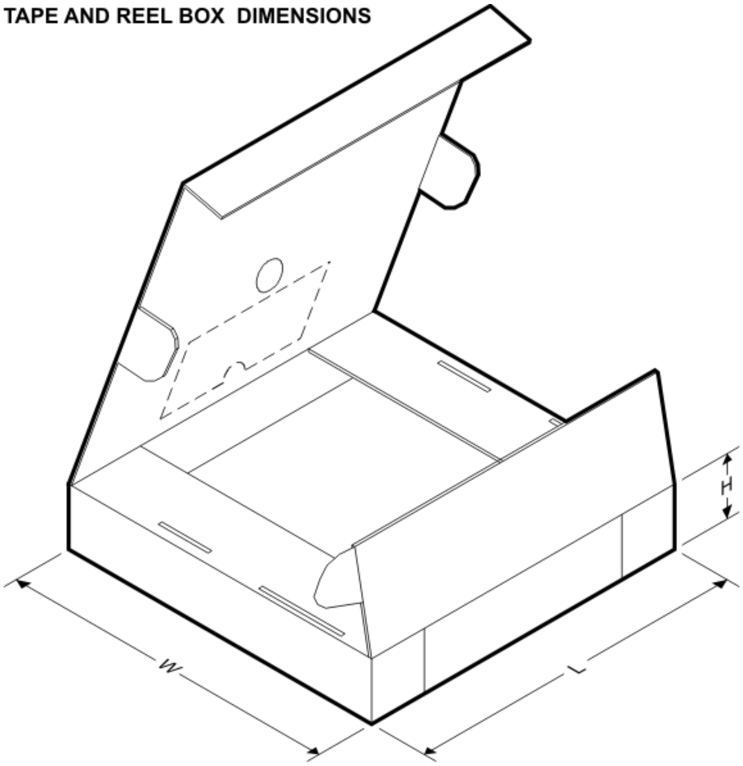
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC5928DBQR	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLC5928PWPR	HTSSOP	PWP	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
TLC5928PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
TLC5928RGER	VQFN	RGE	24	3000	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2
TLC5928RGET	VQFN	RGE	24	250	180.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2

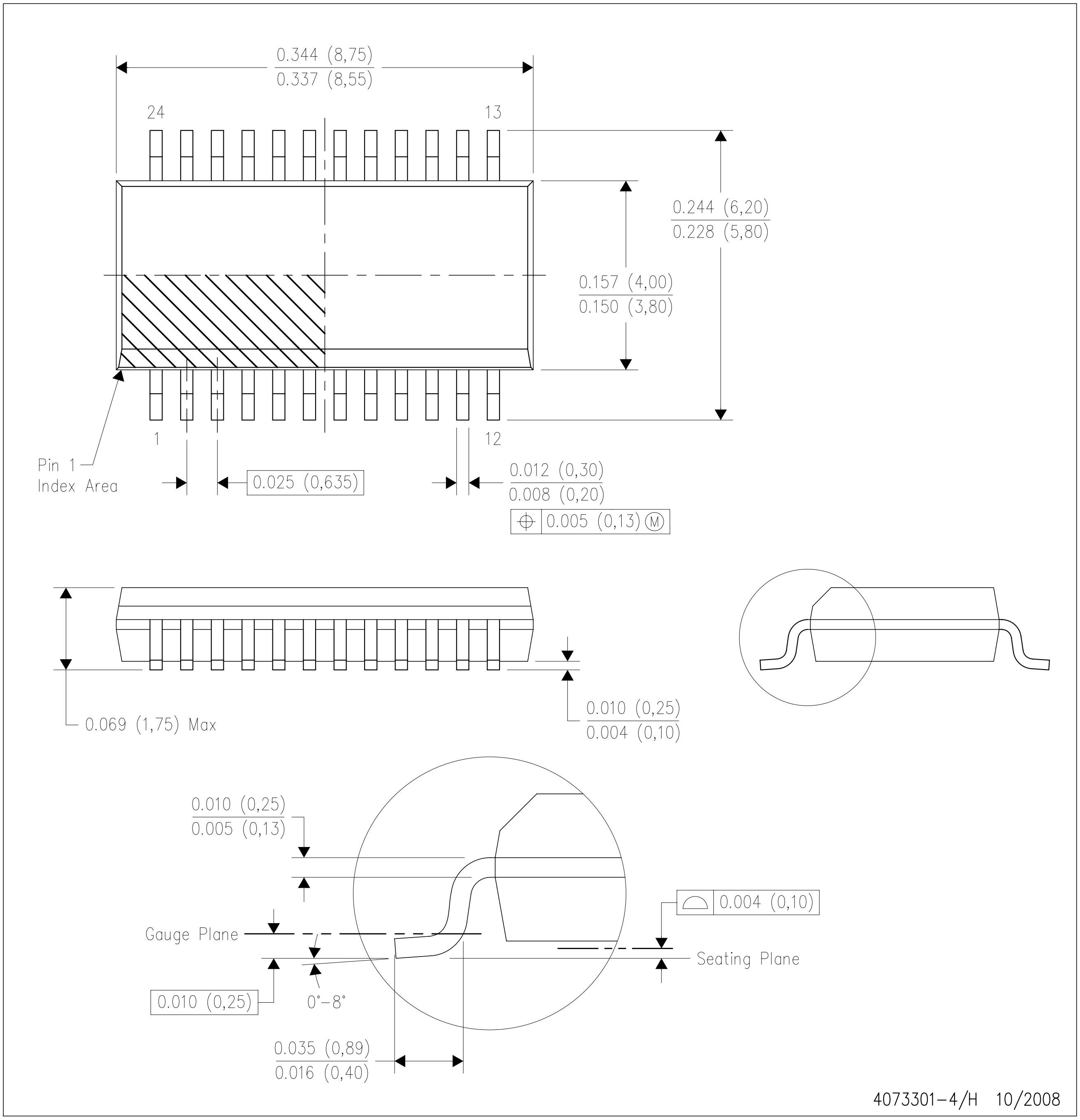
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC5928DBQR	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
TLC5928PWPR	HTSSOP	PWP	24	2000	346.0	346.0	33.0
TLC5928PWR	TSSOP	PW	24	2000	346.0	346.0	33.0
TLC5928RGER	VQFN	RGE	24	3000	346.0	346.0	29.0
TLC5928RGET	VQFN	RGE	24	250	190.5	212.7	31.8

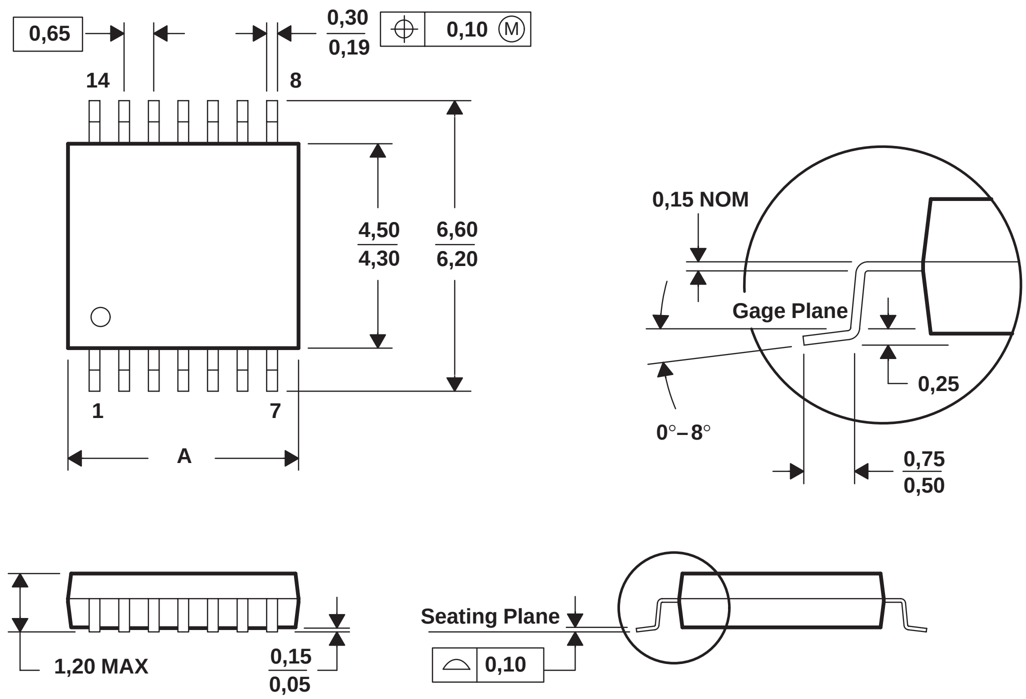
DBQ (R–PDSO–G24) PLASTIC SMALL–OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
D. Falls within JEDEC MO–137 variation AE.

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN

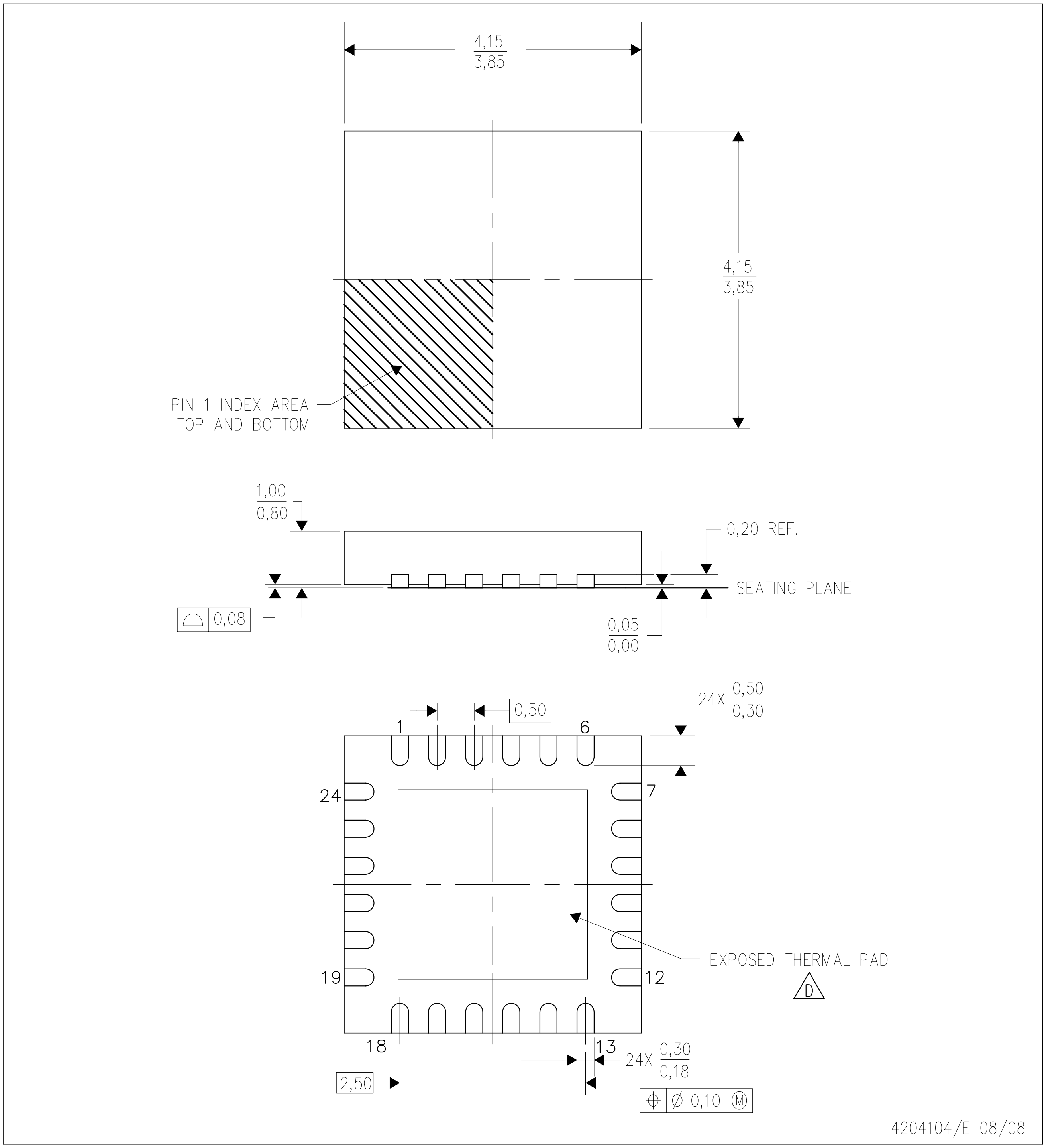


DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

RGE (S–PVQFN–N24) PLASTIC QUAD FLATPACK NO–LEAD



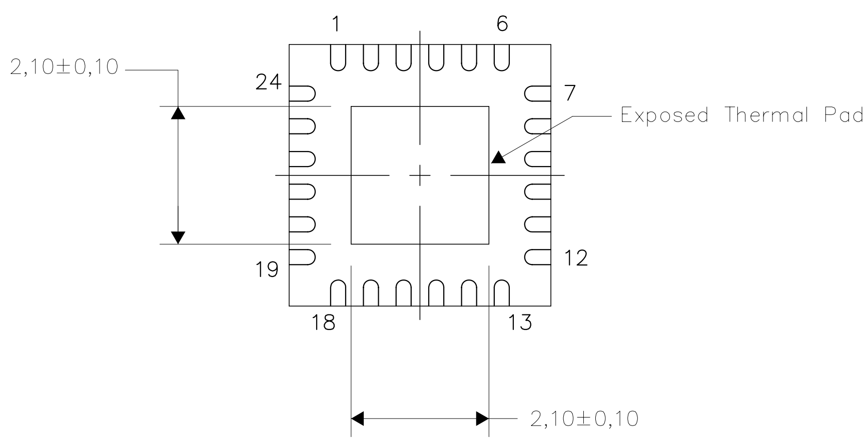
NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No–Leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- E. Falls within JEDEC MO–220.

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



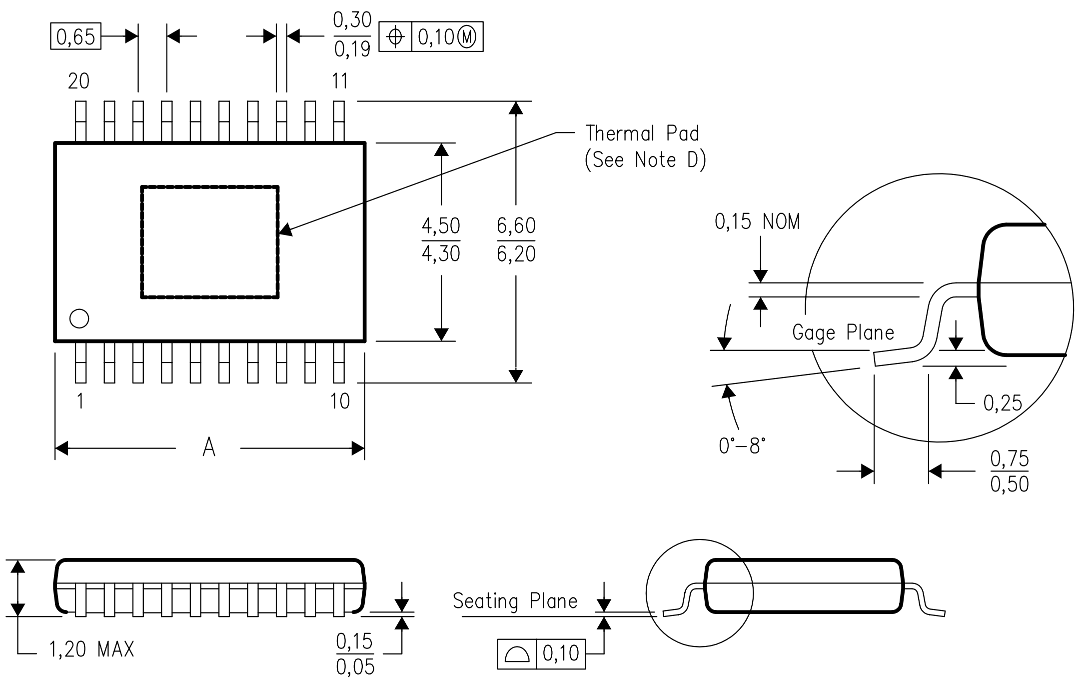
Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

PWP (R-PDSO-G**) PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

20 PIN SHOWN



PINS ** / DIM	14	16	20	24	28
A MAX	5,10	5,10	6,60	7,90	9,80
A MIN	4,90	4,90	6,40	7,70	9,60

4073225/H 12/05

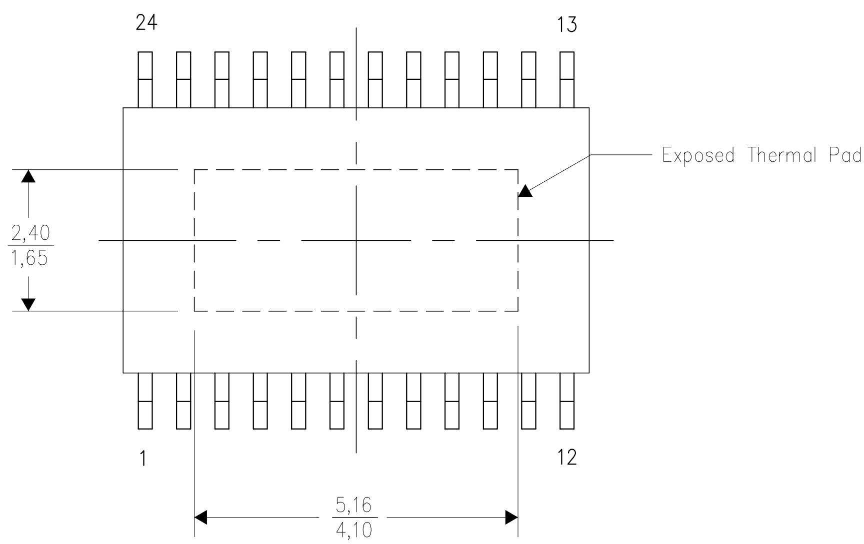
NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http: //www.ti.com>.
- E. Falls within JEDEC MO-153

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions